MICROCHIP MCP6546/6R/6U/7/8/9

Open-Drain Output Sub-Microamp Comparators

Features

- · Low Quiescent Current: 600 nA/comparator (typ.)
- Rail-to-Rail Input: V_{SS} 0.3V to V_{DD} + 0.3V
- Open-Drain Output: $V_{OUT} \le 10V$
- Propagation Delay: 4 µs (typ., 100 mV Overdrive)
- · Wide Supply Voltage Range: 1.6V to 5.5V
- Single available in SOT-23-5, SC-70-5 * packages
- · Available in Single, Dual and Quad
- Chip Select (CS) with MCP6548
- · Low Switching Current
- Internal Hysteresis: 3.3 mV (typ.)
- · Temperature Range:
 - Industrial: -40°C to +85°C
 - Extended: -40°C to +125°C

Typical Applications

- · Laptop Computers
- · Mobile Phones
- · Metering Systems
- · Hand-held Electronics
- · RC Timers
- · Alarm and Monitoring Circuits
- Windowed Comparators
- Multi-vibrators

Related Devices

• CMOS/TTL-Compatible Output: MCP6541/2/3/4

Description

The Microchip Technology Inc. MCP6546/6R/6U/7/8/9 family of comparators is offered in single (MCP6546, MCP6546R, MCP6546U), single with chip select (\overline{CS}) (MCP6548), dual (MCP6547) and quad (MCP6549) configurations. The outputs are open-drain and are capable of driving heavy DC or capacitive loads.

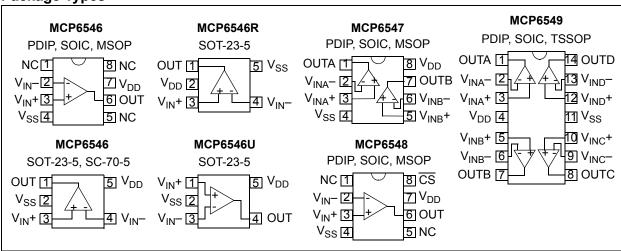
These comparators are optimized for low power, single-supply application with greater than rail-to-rail input operation. The output limits supply current surges and dynamic power consumption while switching. The open-drain output of the MCP6546/6R/6U/7/8/9 family can be used as a level-shifter for up to 10V using a pull-up resistor. It can also be used as a wired-OR logic. The internal Input hysteresis eliminates output switching due to internal noise voltage, reducing current draw. These comparators operate with a single-supply voltage as low as 1.6V and draw a quiescent current of less than 1 μ A/comparator.

The related MCP6541/2/3/4 family of comparators from Microchip has a push-pull output that supports rail-to-rail output swing and interfaces with CMOS/TTL logic.

* SC-70-5 E-Temp parts not available at this release of the data sheet.

MCP6546U SOT-23-5 is E-Temp only.

Package Types



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings †

V _{DD} - V _{SS} 7.0V
Open-Drain outputV _{SS} + 10.5V
Analog Input (V _{IN} +, V _{IN} -)††V _{SS} - 1.0V to V _{DD} + 1.0V
All other inputs and outputs V_{SS} – 0.3V to V_{DD} + 0.3V
Difference Input voltage V _{DD} – V _{SS}
Output Short-Circuit Currentcontinuous
Current at Input Pins±2 mA
Current at Output and Supply Pins±30 mA
Storage temperature65°C to +150°C
Maximum Junction Temperature (T _J)+150°C
ESD protection on all pins:
(HBM;MM)2 kV;200V (MCP6546U)
(HBM;MM) 4 kV; 200V (all other parts)

† Notice: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

†† See Section 4.1.2 "Input Voltage and Current Limits"

DC CHARACTERISTICS

Electrical Specifications: Unless otherwise indicated, V_{DD} = +1.6V to +5.5V, V_{SS} = GND, T_A = 25°C, V_{IN} + = V_{DD} /2, V_{IN} - = V_{SS} , R_{DL} = 2.74 k Ω to V_{DL} = V_{DD} (Refer to Figure 1-3).

$R_{PU} = 2.74 \text{ K}\Omega$ to $V_{PU} = V_{DD}$ (Refer to Figure 1-3).								
Parameters	Sym	Min	Тур	Max	Units	Conditions		
Power Supply								
Supply Voltage	V_{DD}	1.6		5.5	٧	$V_{PU} \ge V_{DD}$		
Quiescent Current	IQ	0.3	0.6	1	μΑ	I _{OUT} = 0		
(per comparator)								
Input								
Input Voltage Range	V _{CMR}	$V_{SS}-0.3$	1	$V_{DD} + 0.3$	٧			
Common Mode Rejection Ratio	CMRR	55	70		dB	V_{DD} = 5V, V_{CM} = -0.3V to 5.3V		
Common Mode Rejection Ratio	CMRR	50	65	_	dB	V_{DD} = 5V, V_{CM} = 2.5V to 5.3V		
Common Mode Rejection Ratio	CMRR	55	70		dB	V_{DD} = 5V, V_{CM} = -0.3V to 2.5V		
Power Supply Rejection Ratio	PSRR	63	80	-	dB	V _{CM} = V _{SS}		
Input Offset Voltage	Vos	-7.0	±1.5	+7.0	mV	V _{CM} = V _{SS} (Note 1)		
Drift with Temperature	$\Delta V_{OS}/\Delta T_{A}$	_	±3		μV/°C	$T_A = -40$ °C to +125°C, $V_{CM} = V_{SS}$		
Input Hysteresis Voltage	V _{HYST}	1.5	3.3	6.5	mV	V _{CM} = V _{SS} (Note 1)		
Linear Temp. Co.	TC ₁	_	6.7		μV/°C	$T_A = -40$ °C to +125°C, $V_{CM} = V_{SS}$ (Note 2)		
Quadratic Temp. Co.	TC ₂	_	-0.035		μV/°C ²	$T_A = -40$ °C to +125°C, $V_{CM} = V_{SS}$ (Note 2)		
Input Bias Current	I _B	_	1		pА	$V_{CM} = V_{SS}$		
At Temperature (I-Temp parts)	I _B	_	25	100	pА	$T_A = +85^{\circ}C, V_{CM} = V_{SS}$ (Note 3)		
At Temperature (E-Temp parts)	I _B	_	1200	5000	pА	$T_A = +125^{\circ}C, V_{CM} = V_{SS}$ (Note 3)		
Input Offset Current	Ios		±1	_	pА	$V_{CM} = V_{SS}$		
Common Mode Input Impedance	Z _{CM}	_	10 ¹³ 4	_	ΩpF			
Differential Input Impedance	Z _{DIFF}		10 ¹³ 2	_	ΩpF			

- **Note** 1: The input offset voltage is the center of the input-referred trip points. The input hysteresis is the difference between the input-referred trip points.
 - 2: V_{HYST} at differential temperatures is estimated using: V_{HYST} (T_A) = V_{HYST} + (T_A -25°C) TC_1 + (T_A 25°C) TC_2 .
 - 3: Input bias current at temperature is not tested for the SC-70-5 package
 - 4: Do not short the output above V_{SS} + 10V. Limit the output current to Absolute Maximum Rating of 30 mA. The minimum V_{PU} test limit was V_{DD} before Dec. 2004 (week code 52).

DC CHARACTERISTICS (CONTINUED)

Electrical Specifications: Unless otherwise indicated, V_{DD} = +1.6V to +5.5V, V_{SS} = GND, T_A = 25°C, V_{IN} + = V_{DD} /2, V_{IN} - = V_{SS} , R_{PU} = 2.74 k Ω to V_{PU} = V_{DD} (Refer to Figure 1-3).

Parameters	Sym	Min	Тур	Max	Units	Conditions	
Open-Drain Output							
Output Pull-Up Voltage	V_{PU}	1.6	_	10	V	(Note 4)	
High-Level Output Current	I _{OH}	-100	_	_	nA	V _{DD} = 1.6V to 5.5V, V _{PU} = 10V (Note 4)	
Low-Level Output Voltage	V _{OL}	V _{SS}	_	V _{SS} + 0.2	V	I_{OUT} = 2 mA, V_{PU} = V_{DD} = 5V	
Short-Circuit Current	I _{SC}	_	±1.5	_	mA	V _{PU} = V _{DD} = 1.6V (Note 4)	
	I _{SC}	_	30	_	mA	V _{PU} = V _{DD} = 5.5V (Note 4)	
Output Pin Capacitance	C _{OUT}	_	8	_	pF		

- **Note** 1: The input offset voltage is the center of the input-referred trip points. The input hysteresis is the difference between the input-referred trip points.
 - 2: V_{HYST} at differential temperatures is estimated using: V_{HYST} (T_A) = V_{HYST} + (T_A -25°C) TC₁ + (T_A 25°C)²TC₂.
 - 3: Input bias current at temperature is not tested for the SC-70-5 package
 - **4:** Do not short the output above V_{SS} + 10V. Limit the output current to Absolute Maximum Rating of 30 mA. The minimum V_{PU} test limit was V_{DD} before Dec. 2004 (week code 52).

AC CHARACTERISTICS

Electrical Specifications: Unless otherwise indicated, $V_{DD} = +1.6V$ to +5.5V, $V_{SS} = GND$, $T_A = 25^{\circ}C$, $V_{IN} + = V_{DD}/2$, Step = 200 mV, Overdrive = 100 mV, $R_{PLI} = 2.74$ k Ω to $V_{PLI} = V_{DD}$, and $C_{L} = 36$ pF (Refer to Figure 1-2 and Figure 1-3).

5.65 250, 6.65, 6.65, 6.65									
Parameters	Sym	Min	Тур	Max	Units	Conditions			
Fall Time	t _F	_	0.7	_	μs	(Note 1)			
Propagation Delay (High-to-Low)	t _{PHL}	_	4.0	8.0	μs				
Propagation Delay (Low-to-High)	t _{PLH}	_	3.0	8.0	μs	(Note 1)			
Propagation Delay Skew	t _{PDS}	_	-1.0	_	μs	(Notes 1 and 2)			
Maximum Toggle Frequency	f _{MAX}	_	225	_	kHz	V _{DD} = 1.6V			
	f _{MAX}	_	165	_	kHz	V _{DD} = 5.5V			
Input Noise Voltage	E _{ni}		200	_	μV _{P-P}	10 Hz to 100 kHz			

- ote 1: t_R and t_{PLH} depend on the load (R_L and C_L); these specifications are valid for the indicated load only.
 - 2: Propagation Delay Skew is defined as: t_{PDS} = t_{PLH} t_{PHL}.

TEMPERATURE CHARACTERISTICS

Electrical Specifications: Unless otherwise indicated, V_{DD} = +1.6V to +5.5V and V_{SS} = GND.								
Parameters	Sym	Min	Тур	Max	Units	Conditions		
Temperature Ranges								
Specified Temperature Range	T_A	-40		+85	°C			
Operating Temperature Range	T_A	-40	_	+125	°C	Note		
Storage Temperature Range	T_A	-65	_	+150	°C			
Thermal Package Resistances								
Thermal Resistance, 5L-SC-70	$\theta_{\sf JA}$	_	331	_	°C/W			
Thermal Resistance, 5L-SOT-23	$\theta_{\sf JA}$	_	256	_	°C/W			
Thermal Resistance, 8L-PDIP	$\theta_{\sf JA}$	_	85	_	°C/W			
Thermal Resistance, 8L-SOIC	θ_{JA}	_	163	_	°C/W			
Thermal Resistance, 8L-MSOP	θ_{JA}	_	206	_	°C/W			
Thermal Resistance, 14L-PDIP	θ_{JA}	_	70	_	°C/W			
Thermal Resistance, 14L-SOIC	θ_{JA}	_	120	_	°C/W			
Thermal Resistance, 14L-TSSOP	$\theta_{\sf JA}$	_	100	_	°C/W			

Note: The MCP6546/6R/6U/7/8/9 I-temp family operates over this extended temperature range, but with reduced performance. In any case, the Junction Temperature (T_J) must not exceed the absolute maximum specification of +150°C.

1.1 Test Circuit Configuration

This test circuit configuration is used to determine the AC and DC specifications.

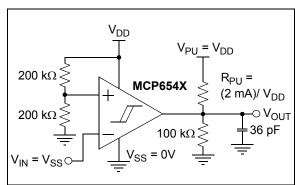
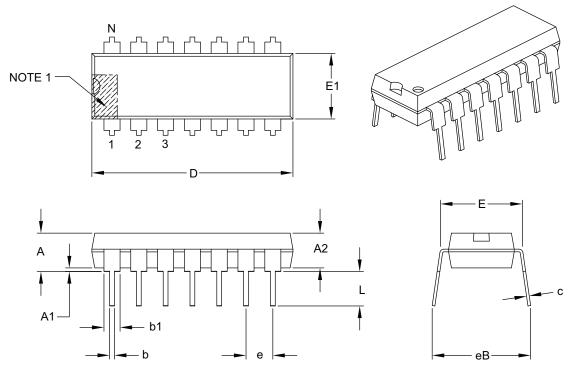


FIGURE 1-3: AC and DC Test Circuit for the Open-Drain Output Comparators.

14-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]



	Units	INCHES				
	Dimension Limits	MIN	NOM	MAX		
Number of Pins	N		14			
Pitch	е		.100 BSC			
Top to Seating Plane	A	-	_	.210		
Molded Package Thickness	A2	.115	.130	.195		
Base to Seating Plane	A1	.015	_	_		
Shoulder to Shoulder Width	E	.290	.310	.325		
Molded Package Width	E1	.240	.250	.280		
Overall Length	D	.735	.750	.775		
Tip to Seating Plane	L	.115	.130	.150		
Lead Thickness	С	.008	.010	.015		
Upper Lead Width	b1	.045	.060	.070		
Lower Lead Width	b	.014	.018	.022		
Overall Row Spacing §	eB	_	_	.430		

Notes:

- 1. Pin 1 visual index feature may vary, but must be located with the hatched area.
- 2. § Significant Characteristic.
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-005B

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	<u>–X</u> / <u>XX</u>	Exa	amples:	
	perature Package ange	a)	MCP6546T-I/LT:	Tape and Reel, Industrial Temperature, 5LD SC-70.
Device:	MCP6546: Single Comparator MCP6546T: Single Comparator (Tape and Reel)	b)	MCP6546T-I/OT:	Tape and Reel, Industrial Temperature, 5LD SOT-23.
	(SC-70, SOT-23, SOIC, MSOP) MCP6546RT: Single Comparator (Rotated - Tape and	c)	MCP6546-E/P:	Extended Temperature, 8LD PDIP.
	Reel) (SOT-23 only) MCP6546UT: Single Comparator (Tape and Reel) (SOT-23-5 is E-Temp only) MCP6547: Dual Comparator	d)	MCP6546RT-I/OT:	Tape and Reel, Industrial Temperature, 5LD SOT23.
	MCP6547T: Dual Comparator (Tape and Reel for SOIC and MSOP)	e)	MCP6546-E/SN:	Extended Temperature, 8LD SOIC.
	MCP6548: Single Comparator with CS MCP6548T: Single Comparator with CS (Tape and Reel for SOIC and MSOP) MCP6549: Quad Comparator MCP6549T: Quad Comparator	f)	MCP6546UT-E/OT	F:Tape and Reel, Extended Temperature, 5LD SOT23.
	(Tape and Reel for SOIC and TSSOP)	a)	MCP6547-I/MS:	Industrial Temperature, 8LD MSOP.
emperature Range:	= -40°C to +85°C E* = -40°C to +125°C	b)	MCP6547T-I/MS:	Tape and Reel, Industrial Temperature, 8LD MSOP.
	* SC-70-5 E-Temp parts not available at this release of the data sheet.	c)	MCP6547-I/P:	Industrial Temperature, 8LD PDIP.
Package:	LT = Plastic Package (SC-70), 5-lead OT = Plastic Small Outline Transistor (SOT-23), 5-lead MS = Plastic MSOP, 8-lead P = Plastic DIP (300 mil Body), 8-lead, 14-lead	d)	MCP6547-E/SN:	Extended Temperature, 8LD SOIC.
	SN = Plastic SOIC (150 mil Body), 8-lead, 14-lead (SL = Plastic SOIC (150 mil Body), 14-lead (MCP6549) ST = Plastic TSSOP (4.4mm Body), 14-lead (MCP6549)	a)	MCP6548-I/SN:	Industrial Temperature, 8LD SOIC.
		b)	MCP6548T-I/SN:	Tape and Reel, Industrial Temperature, 8LD SOIC.
		c)	MCP6548-I/P:	Industrial Temperature, 8LD PDIP.
		d)	MCP6548-E/SN:	Extended Temperature, 8LD SOIC.
		a)	MCP6549T-I/SL:	Tape and Reel, Industrial Temperature, 14LD SOIC.
		b)	MCP6549T-E/SL:	Tape and Reel, Extended Temperature, 14LD SOIC.
		c)	MCP6549-I/P:	Industrial Temperature, 14LD PDIP.
		d)	MCP6549-E/ST:	Extended Temperature, 14LD TSSOP.